vovaga

2SC6097-TL-E

Data Sheet

<u>RFO</u>

Trans GP BJT NPN 60V 3A 800mW 3-Pin(2+Tab) TP-FA T/R

Trans GP BJT NPN 60V 3A 800mW 3-Pin(2+Tab) TP-FA T/R		6.5 5.0 4 4 5.0 5.0 5.0 5.0 5.0 5.0 5.0 5.0 5.0 5.0
Manufacturers	ON Semiconductor, LLC	
Package/Case	SC-63	0.6 1 2 3 0.6 1 3 0.6 1 2 1 3 0.6 1 3
Product Type	Transistors	3 : Emitter 4 : Collector TP-FA
RoHS	Rohs	Images are for reference only
Lifecycle		
Please submit RFQ for 2SC6097-TL-E or Email to us: sales@ovaga.com We will contact you in 12 hours.		

General Description

2SC6097 is a Bipolar Transistor, 60V, 3A, Low VCE(sat), NPN Single TP/TP-FA for high current switching applications.

Features

High current capacitance

Adoption of FBET, MBIT process

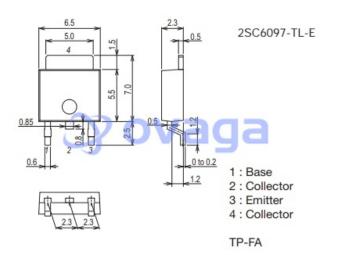
Low collector-to-emitter saturation voltage

High allowable power dissipation

High-speed switching

Application

ONSEMI





Related Products



<u>2SC4027S-TL-Е</u>

ON Semiconductor, LLC TO-252



2SC4135T-E ON Semiconductor, LLC

TO-251



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2SC5964-TD-E ON Semiconductor, LLC

SOT-89

<u>2SA2125-TD-Е</u>

ON Semiconductor, LLC SOT-89





<u>2SC5707-Е</u>

ON Semiconductor, LLC TO-251

2SD1815S-TL-E

ON Semiconductor, LLC TO-252

2SC3648S-TD-E

ON Semiconductor, LLC SOT-89

2SA2016-TD-E

ON Semiconductor, LLC SOT-89-3



Ovaga Technologies Limited